Constantes y aclaraciones

$G(x) = \frac{dN}{dx} = \text{dens. de est.}; \quad g(x) = \frac{dn}{dx} = \frac{\text{dens. de est.}}{V}$

$k_B = 1.381 \times 10^{-23} JK^{-1} = 8.62 \times 10^{-5} eVK^{-1}$

$m_e = 9.11 \times 10^{-31} kg = 0.511 MeVc^{-2}$

$m_p = 1.67 \times 10^{-27} kg = 938 MeVc^{-2}$

$\varepsilon_0 = \frac{1}{4\pi K} = 8.85 \times 10^{-12} Fm^{-1}$

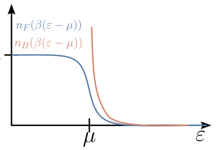
$\hbar = 1.055 \times 10^{-34} Js = 6.58 \times 10^{-16} eVs$

$e = 1.602 \times 10^{-19} C$

Fermions: $e^-, p, n \quad (n_F(x) = \frac{1}{e^x + 1})$

Bosons: phonon, photon $\quad (n_B(x) = \frac{1}{e^x - 1})$

$n \sim 10^{22} cm^{-3}; \tau \sim 10^{-15} s; v \sim 10^{-5} \frac{m}{s}$



<u>T bajas</u>

$n_F(x) \approx n_B(x) \approx e^{-x}$

<u>T altas</u>

$n_F(x) \approx \frac{1}{2+x}$

$n_B(x) \approx \frac{1}{x}$

1 Estructura cristalina

1.1 Redes de Bravais

a	triclínica
m	monoclínica
o	ortorómbica
t	tetragonal
h	hexagonal
c	cúbica

P	Primitiva
S	Centrada en una cara
I	Centrada en el cuerpo
R	Centrada romboidal
F	Centrada en las caras

14 posibles redes de Bravais

Tric.	Monoc.	Ortor.	Tetra.	Hex.	Cúbico
aP	mP, mS	oP, oS, oF, oI	tP, tI	hP, hR	cP, cF, cI

1.2 Cosas

Base dual y matriz métrica

$$a^* = \frac{b \times c}{V}, \quad b^* = \frac{c \times a}{V}, \quad c^* = \frac{a \times b}{V}, \quad V = \det(\bar{a}, \bar{b}, \bar{c})$$

$$(\bar{a}^*, \bar{b}^*, \bar{c}^*) = \begin{pmatrix} \bar{a}^T \\ \bar{b}^T \\ \bar{c}^T \end{pmatrix}^{-1}, G = \begin{pmatrix} a \cdot a & a \cdot b & a \cdot c \\ b \cdot a & b \cdot b & b \cdot c \\ c \cdot a & c \cdot b & c \cdot c \end{pmatrix}, G^* = G^{-1}$$

Cambio de base

$$(\bar{a}', \bar{b}', \bar{c}') = (\bar{a}, \bar{b}, \bar{c})P, \quad \begin{pmatrix} x' \\ y' \\ z' \end{pmatrix} = P^{-1} \begin{pmatrix} x \\ y \\ z \end{pmatrix}$$

$$(x, y, z) = (x^*, y^*, z^*)P, \quad \begin{pmatrix} a'^* \\ b'^* \\ z'^* \end{pmatrix} = P^{-1} \begin{pmatrix} a^* \\ b^* \\ c^* \end{pmatrix}$$

Distancia interplanar $g_{hkl} = \frac{1}{d_{hkl}}; \quad g^2_{hkl} = (hkl)G^* \begin{pmatrix} h \\ k \\ l \end{pmatrix}$

Transferencia de momento $Q = \frac{4\pi \sin\theta}{\lambda}$

Condiciones de Laue $\overline{Q} = 2\pi \overline{g}_{hkl}$

Ley de Bragg $g_{hkl} = \frac{2 \sin\theta_{hkl}}{\lambda}$

Módulo de Young $\nu_s = \sqrt{\frac{\gamma}{\rho}}$

Factor de estructura $F_{hkl} = \sum_p f_p e^{-i2\pi \overline{g}_{hkl} \cdot \overline{r}_p}; I \propto |F_{hkl}|^2$

1.3 Estructuras comunes

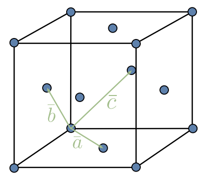
FCC (primitiva volumen 1/4)

$$\begin{cases} \bar{a} = \frac{1}{2}(1\ 1\ 0) \\ \bar{b} = \frac{1}{2}(0\ 1\ 1) \\ \bar{c} = \frac{1}{2}(1\ 0\ 1) \end{cases} \qquad \begin{cases} \bar{a}^* = (1\ 1\ -1) \\ \bar{b}^* = (-1\ 1\ 1) \\ \bar{c}^* = (1\ -1\ 1) \end{cases}$$

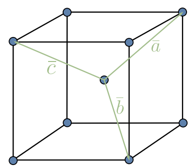
BCC (primitiva volumen 1/2)

$$\begin{cases} \bar{a} = \frac{1}{2}(1\ 1\ -1) \\ \bar{b} = \frac{1}{2}(-1\ 1\ 1) \\ \bar{c} = \frac{1}{2}(1\ -1\ 1) \end{cases} \qquad \begin{cases} \bar{a}^* = (1\ 1\ 0) \\ \bar{b}^* = (0\ 1\ 1) \\ \bar{c}^* = (1\ 0\ 1) \end{cases}$$

FCC



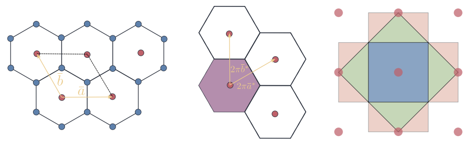
BCC



Hexagonal

$$\begin{cases} \bar{a} = (1, 0) \\ \bar{b} = (-\frac{1}{2}, \frac{\sqrt{3}}{2}) \end{cases} \qquad \begin{cases} \bar{a}^* = \frac{2\sqrt{3}}{3}(\frac{\sqrt{3}}{2}, \frac{1}{2}) \\ \bar{b}^* = \frac{2\sqrt{3}}{3}(0, 1) \end{cases}$$

$$G = \begin{pmatrix} a^2 & -\frac{a^2}{2} & 0 \\ -\frac{a^2}{2} & a^2 & 0 \\ 0 & 0 & c^2 \end{pmatrix}, \quad G^* = \begin{pmatrix} \frac{4}{3a^2} & \frac{2}{3a^2} & 0 \\ \frac{2}{3a^2} & \frac{4}{3a^2} & 0 \\ 0 & 0 & \frac{1}{c^2} \end{pmatrix}$$



En una hcp $c = 1.633a$

1.4 Grupos

$$m_{100} = \begin{pmatrix} -1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 1 \end{pmatrix}; n_{001} = \begin{pmatrix} \cos\left(\frac{360}{n}\right) & -\sin\left(\frac{360}{n}\right) & 0 \\ \sin\left(\frac{360}{n}\right) & \cos\left(\frac{360}{n}\right) & 0 \\ 0 & 0 & 1 \end{pmatrix}$$

Cambio de base a $\mathcal{B} = \{\overline{u}, \overline{v}, \overline{w}\}$

$$M_{\mathcal{C}} = M_{\mathcal{B} \to \mathcal{C}} M_{\mathcal{B}} M^{-1}_{\mathcal{B} \to \mathcal{C}}, \quad M_{\mathcal{B} \to \mathcal{C}} = (\overline{u}, \overline{v}, \overline{w})$$

Reflexión vector director (a, b, c)

$$M = \frac{1}{a^2 + b^2 + c^2} \begin{pmatrix} -a^2 + b^2 + c^2 & -2ab & -2ac \\ -2ab & a^2 - b^2 + c^2 & -2bc \\ -2ac & -2bc & a^2 + b^2 - c^2 \end{pmatrix}$$

Rotación respecto $\hat{u} = (u_x, u_y, u_z)$ $(c = \cos\theta, \quad s = \sin\theta)$.

$R =$

$$\begin{pmatrix} c + u_x^2(1-c) & u_x u_y(1-c) - u_z s & u_x u_z(1-c) + u_y s \\ u_y u_x(1-c) + u_z s & c + u_y^2(1-c) & u_y u_z(1-c) - u_x s \\ u_z u_x(1-c) - u_y s & u_z u_y(1-c) + u_x s & c + u_z^2(1-c) \end{pmatrix}$$

Centrosimétricos $(x, y, z) \to (-x, -y, -z)$ no tienen polarización espontánea

2 Dinámica de cristales

2.1 Densidad de estados

$$\overline{k} = \left(\tfrac{2\pi}{L}n \quad \tfrac{2\pi}{L}m \quad \tfrac{2\pi}{L}l\right) \ \forall n, m, l \in \mathbb{Z}$$

Número de estados hasta k

$$N(k) = \int_{(\frac{2\pi}{L})^2(n^2+m^2+l^2) \leq k^2} dV = \frac{L^3}{6\pi^2}k^3 = \frac{V}{6\pi^2}k^3$$

1, 2 y 3 dimensiones respectivamente (y se cumple $\omega = \nu_s k$)

$$\begin{cases} G(k) = \frac{L}{\pi} \\ G(\omega) = \frac{L}{\pi\nu} \end{cases} \quad \begin{cases} G(k) = \frac{L^2}{2\pi}k \\ G(\omega) = \frac{L^2}{2\pi\nu^2}\omega \end{cases} \quad \begin{cases} G(k) = \frac{V}{2\pi^2}k^2 \\ G(\omega) = \frac{V}{2\pi^2\nu_s^3}\omega^2 \end{cases}$$

2.2 Dispersión

Oscilador con masa m y constante k_s

$$F_n = m\ddot{x}_n = k_s(x_{n+1} + x_{n-1} - 2x_n)$$

$$-m\omega^2 Ae^{i(kna-\omega t)} = k_s Ae^{i(kna-\omega t)}(e^{ika} + e^{-ika} - 2) =$$

$$= -4k_s \sin^2\left(\frac{ka}{2}\right) \Rightarrow \boxed{\omega = 2\sqrt{\frac{k_s}{m}}\left|\sin\left(\frac{ka}{2}\right)\right|}$$

Oscilador con masa m y constantes alternadas k_1, k_2

$$\begin{cases} m\ddot{x}_n = k_1(y_{n-1} - x_n) + k_2(y_n - x_n) \\ m\ddot{y}_n = k_1(x_{n+1} - y_n) + k_2(x_n - y_n) \end{cases}$$

Ansatz

$$x_n = Ae^{i(kna-\omega t)} \qquad y_n = Be^{i(kna-\omega t)}$$

Ecuaciones

$$\begin{cases} -m\omega^2 A = -A(k_1 + k_2) + B(k_1 e^{ika} + k_2) \\ -m\omega^2 B = -A(k_1 e^{ika} + k_2) + B(-k_1 - k_2) \end{cases}$$

Forma matricial

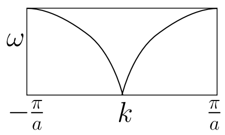
$$m\omega^2 \begin{pmatrix} A \\ B \end{pmatrix} = \begin{pmatrix} (k_1 + k_2) & -k_2 - k_1 e^{ika} \\ -k_2 - k_1 e^{ika} & (k_1 + k_2) \end{pmatrix} \begin{pmatrix} A \\ B \end{pmatrix} = K \begin{pmatrix} A \\ B \end{pmatrix}$$

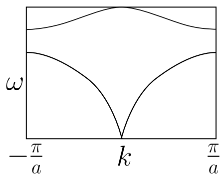
$$0 = \det(K - m\omega^2 I) = |(k_1 + k_2) - m\omega^2|^2 - |k_2 + k_1 e^{ika}|^2$$

$$\boxed{\omega_\pm(k) = \sqrt{\frac{k_1 + k_2}{m} \pm \frac{1}{m}\sqrt{(k_1 + k_2)^2 - 4k_1 k_2 \sin^2(ka/2)}}}$$

Si $m_1 \neq m_2$ y k_s es la misma, sea $K_i = \frac{k}{m_i}$, entonces

$$\boxed{\omega_\pm(k) = \sqrt{(K_1 + K_2) \pm \sqrt{(K_1 + K_2)^2 - 4K_1 K_2 \sin^2(ka/2)}}}$$





Si hay N átomos / celda: $3N$ ramas:

- 3 acústicas (2 trans. $<$ 1 long.)
- $3N - 3$ ópticas

2.3 Modelo de Einstein

$$E_n = \hbar\omega(n + \frac{1}{2}) \quad \Rightarrow \quad Z_1 = \frac{1}{2\sinh(\frac{\beta\hbar\omega}{2})}$$

$$\langle E_1 \rangle = -\frac{\partial}{\partial\beta}\ln Z_1 = \frac{\hbar\omega}{2}\coth\left(\frac{\beta\hbar\omega}{2}\right)$$

Energía y capacidad calorífica

$$\langle E \rangle = \frac{3}{2}N\hbar\omega\coth\left(\frac{\beta\hbar\omega}{2}\right)$$

$$C_v = \frac{\partial\langle E \rangle}{\partial T} = 3Nk_B(\beta\hbar\omega)^2\frac{e^{\beta\hbar\omega}}{(e^{\beta\hbar\omega} - 1)^2}$$

Definimos ahora $T_E = \frac{\hbar\omega_E}{k_B}$. En los límites

- Si $T \gg T_E \quad \Rightarrow \quad C_v = 3Nk_b$
- Si $T \ll T_E \quad \Rightarrow \quad C_v = 3Nk_b(\frac{T_E}{T})^2\frac{1}{\sinh^2(\frac{T_E}{2T})}$

2.4 Modelo de Debye

Aproximamos la ecuación de dispersión para k baja como $\omega = \nu k$

$$3N = \int_0^{\omega_D} 3G(\omega)d\omega = \frac{V}{2\pi^2\nu^3}\omega_D^3 \Rightarrow \boxed{\omega_D = \sqrt[3]{\frac{6\pi^2\nu^3 N}{V}}}$$

donde hemos contado cada partícula y cada estado 3 veces y hemos usado

$$\omega = \nu k, \qquad G(k) = \frac{V}{2\pi^2}k^2, \qquad G(\omega) = \frac{V}{2\pi^2\nu^3}\omega^2 = 3N\frac{\omega^2}{\omega_D^3}$$

La energía y la capacidad calorífica

$$\langle E\rangle = \int_0^{\omega_D} \hbar\omega 3G(\omega)\left(\frac{1}{e^{\beta\hbar\omega}-1}+\frac12\right)d\omega =$$
$$= E_0 + \frac{3V\hbar}{2\pi^2\nu^3}\int_0^{\omega_D}\frac{\hbar\omega^3}{e^{\beta\hbar\omega}-1}d\omega \qquad (x=\frac{\hbar\omega}{k_BT})$$
$$T_D := \frac{\hbar\omega_D}{k_B} \quad\Rightarrow \boxed{\langle E\rangle = \frac{3Vk_B^4T^4}{2\pi^2\nu^3\hbar^3}\int_0^{\frac{T_D}{T}}\frac{x^3}{e^x-1}dx}$$

La capacidad calorífica $C_v = \frac{\partial\langle E\rangle}{\partial T}$ en los extremos:

- Si $T\gg T_D \Rightarrow \langle E\rangle\sim 3Nk_BT \Rightarrow C_v\sim 3Nk_B$
- Si $T\ll T_D \Rightarrow \langle E\rangle \sim \frac{3\pi^4Nk_BT^4}{5T_D^3} \Rightarrow C_v \sim \frac{12\pi^4}{5}Nk_B\left(\frac{T}{T_D}\right)^3$

3 Electrones en los sólidos

Modelo de Drude

$$n=\frac{N}{V};\quad \frac{dp}{dt}=-\frac{p}{\tau}+F;\quad \bar j = -ne\bar v = \sigma\bar E$$
$$\sigma_0=\frac{e^2\tau n}{m};\quad \text{si } F-e\mathrm{Re}[E_0e^{i\omega t}]\Rightarrow\sigma(\omega)=\frac{\sigma_0}{1-i\omega t}$$
$$mv=p=-e\tau E;\quad R_H=\frac{-1}{ne}=\frac{\rho_{yx}}{|B|}$$
$$\bar E=\tilde\rho\bar j;\quad \rho_{xx}=\rho_{yy}=\rho_{zz}\frac{m}{ne^2\tau};\quad \frac12 mv_0^2=\frac32k_BT$$

Efecto Hall (2 portadores con la misma carga opuesta)

$$\mu_i=\frac{\tau_i}{m_i};\quad \sigma=ne^2(\mu_1+\mu_2);\quad R_H=\frac{\mu_2^2-\mu_1^2}{n_0e(\mu_1+\mu_2)^2}e^{\beta E}$$

Hall resistivity $\rho_{xy}=-\rho_{yx}=\frac{B}{ne}$ $(\bar B\propto\hat z)$

Peltier coefficient $\Pi=-\frac{k_BT}{2e}=\frac{-c_vT}{3e}$

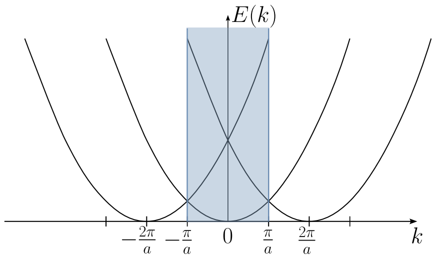
Seebeck coefficient $S=\frac{\Pi}{T}$

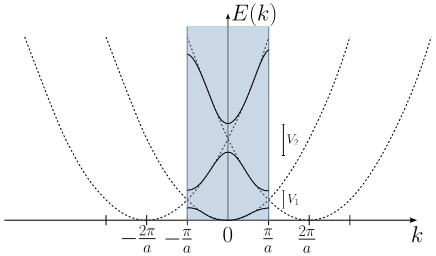
$$\langle v\rangle_{gasid.}=\sqrt{\frac{8k_BT}{\pi m}};\quad \kappa=\frac13nc\langle v\rangle^2\tau=\frac4\pi\frac{n\tau k_B^2T}{m}$$

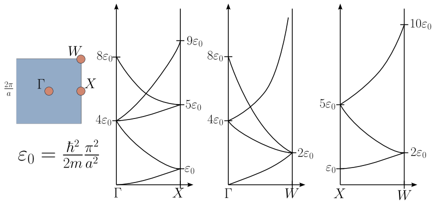
Capacidad Calorífica

$$g(\varepsilon)=\frac{3n}{2(E_F)^{\frac32}}\varepsilon^{\frac12}=\frac{(2m)^{\frac32}}{2\pi^2\hbar^3}\varepsilon^{\frac12},\quad k=\sqrt{\frac{2\varepsilon m}{\hbar^2}}$$
$$n=\int_0^\infty d\varepsilon g(\varepsilon)n_F(\beta(\varepsilon-\mu)),\quad \frac{E_T}{V}=\int_0^\infty d\varepsilon\varepsilon g(\varepsilon)n_F(\beta(\varepsilon-\mu))$$
$$C=\frac{\pi^2}{3}\left(\frac{3Nk_B}{2}\right)\left(\frac{T}{T_F}\right)$$

$$\bar M=g(E_F)\mu_B^2\bar B;\quad \mu_B=0.67\left(\frac{K}{Tesla}\right)k_B$$







Teorema de Bloch ($V(\bar r)$ periódico)

$$\psi_{\bar k}(\bar r)=u_{\bar k}(\bar r)e^{i\bar k\cdot\bar r},\quad E(\bar k)=E(\bar k+\bar G)$$

(1D) Fourier del potencial de dos formas

$$V(x)=V_0+\sum_{j=1}^\infty V_j\cos\left(\frac{2\pi j}{a}x\right)\quad \text{ó}\quad V(x)=\sum_{j=-\infty}^{\infty}V_{\frac{2\pi j}{a}}e^{i\frac{2\pi j}{a}x}$$

Con las relaciones $V_j=2V_{\frac{2\pi j}{a}}$, y donde los coeficientes son

$$V_j=\frac2a\int_{-\frac a2}^{\frac a2}dxV(x)\cos\left(\frac{2\pi j}{a}x\right);\quad V_{\frac{2\pi j}{a}}=\frac1a\int_{-\frac a2}^{\frac a2}dxV(x)e^{-i\frac{2\pi j}{a}x}$$

Gas de electrones libres

$$\bar k=\frac{2\pi}{L}(n_x,n_y,n_z),\quad E(\bar k)=\frac{\hbar^2}{2m}|\bar k|^2,\quad n_F(x)=\frac{1}{e^x+1}$$
$$N=2\sum_{\bar k}n_F(\beta(E(\bar k)-\mu))=2\frac{V}{(2\pi)^3}\int d\bar k n_F(\beta(E(\bar k)-\mu))$$

Fermi energy ($E_F=\mu(T\to0)$) (d numero de dimensiones)

$$\varepsilon_F=\frac{\hbar^2k_F^2}{2m}=k_BT_F;\quad p_F=\hbar k_F;\quad U_T=\frac35\varepsilon_FN$$
$$N=2\frac{V}{(2\pi)^d}\int_{|k|<k_F}dk\Rightarrow k_F=(3\pi^2n)^{\frac13},\quad \varepsilon_F=\frac{\hbar^2(3\pi^2n)^{\frac23}}{2m}$$

Considerando los dos espines (multiplicamos por 2)

$$N_T=2\cdot\left(\frac43\pi(n_x^2+n_y^2+n_z^2)^{3/2}\right)\quad\Rightarrow\quad k_{max}^2=k_F^2=(3n\pi^2)^{\frac23}$$

e^- excitados por encima de ε_F

$$n_{e^-}=2\cdot\frac12\cdot(2k_BT)(\frac12 g(\varepsilon_F))=k_BTg(\varepsilon_F);\quad \frac{n_{e^-}}{n}=\frac34\frac{k_BT}{\varepsilon_F}$$

Electrones casi-libres

$$\psi_+\sim\cos(\pi\frac xa),\quad \psi_-\sim\sin(\pi\frac xa)$$
$$E^\pm=\frac12(E^0_{\bar k-\bar G}+E^0_{\bar k})\pm\sqrt{\frac14(E^0_{\bar k-\bar G}-E^0_{\bar k})^2+|V_{\bar G}|^2}$$

Enlace fuerte, celda primitiva cúbica ($B=\gamma, A=\beta$)

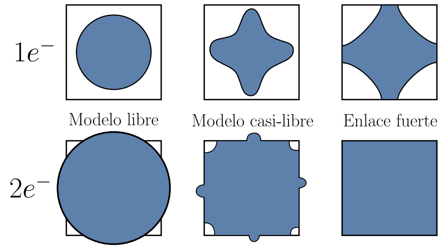
$$\varepsilon(\bar k)=E-\left(\frac{\beta+\sum_{r_i\neq0}\gamma(r_i)e^{i\bar k\cdot\bar r_i}}{1+\sum_{r_i\neq0}\alpha(r_i)e^{i\bar k\cdot\bar r_i}}\right)$$
$$E(\bar k)\approx E_i-A-2B(\cos k_xa+\cos k_ya+\cos k_za)$$
$$A=-\langle\varphi_{i,n}|v|\varphi_{i,n}\rangle,\quad B=-\langle\varphi_{i,m}|v|\varphi_{i,n}\rangle$$
$$\bar v=\nabla_{\bar k}\omega(\bar k)=\frac1\hbar\nabla_{\bar k}E(\bar k)$$

Carga de un campo $\bar{\mathcal E}$

$$\dot v_i=\frac{1}{\hbar^2}\sum_j\frac{\partial^2E}{\partial k_i\partial k_j}(-e\mathcal E_j),\quad \left(\frac{1}{m^*}\right)_{ij}=\frac{1}{\hbar^2}\frac{\partial^2E(\bar k)}{\partial k_i\partial k_j}$$

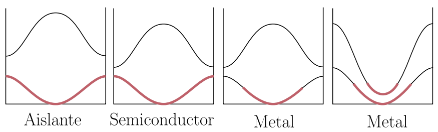
Caso totalmente degenerado

$$m^*=\frac{\hbar^2}{\left(\frac{d^2E}{dk^2}\right)},\quad E(\bar k)=E_0+\frac{\hbar^2}{2m^*}|k|^2,\quad \sigma\simeq\frac{e^2\tau(E_F)n}{m^*}$$



Tipos de materiales

Aislante: Banda llena ($2e^-$). $V_g>4eV$
Semiconductor Banda llena ($2e^-$). $V_g<4eV$.
Metal Banda semillena ($1e^2$ ó $2e^-$ con bandas solapantes).



4 Semiconductores

extrínseco = dopado
Opacos si $h\nu>E_g$
Nivel de Fermi $E_F=\mu$
Densidad de estados (n electrones, p holes)
Energía de donadores / impurezas E_D

n (negativo)	N_C (conducción)	N_D (donadores)
p (positivo)	N_V (valencia)	N_A (aceptores)

$$g_C(\varepsilon)=\frac{(2m_n^*)^{2/3}}{2\pi^2\hbar^3}\sqrt{\varepsilon-\varepsilon_C};g_V(\varepsilon)=\frac{(2m_p^*)^{2/3}}{2\pi^2\hbar^3}\sqrt{\varepsilon_V-\varepsilon}$$
$$n=\int_{\varepsilon_C}^\infty d\varepsilon g_C(\varepsilon)n_F(\beta(\varepsilon-\mu))\approx\int_{\varepsilon_C}^\infty d\varepsilon g_C(\varepsilon)e^{\beta(\mu-\varepsilon)}$$
$$p=\int_{-\infty}^{\varepsilon_V}d\varepsilon g_V(\varepsilon)(1-n_F(\beta(\varepsilon-\mu)))\approx\int_{-\infty}^{\varepsilon_V}d\varepsilon g_V(\varepsilon)e^{\beta(\varepsilon-\mu)}$$
$$n=\frac14\left(\frac{2m_n^*k_BT}{\pi\hbar^2}\right)^{3/2}e^{\beta(\mu-\varepsilon_C)}=N_Ce^{\beta(\mu-\varepsilon_C)}$$
$$p=\frac14\left(\frac{2m_p^*k_BT}{\pi\hbar^2}\right)^{3/2}e^{\beta(\varepsilon_V-\mu)}=N_Ve^{\beta(\varepsilon_V-\mu)}$$
$$np=N_CN_Ve^{-\beta E_g}=4\left(\frac{k_BT}{2\pi\hbar^2}\right)^3(m_n^*m_p^*)^{3/2}e^{-\beta E_g}$$
$$e^{2\beta\mu}=\frac{N_V}{N_C}e^{\beta(\varepsilon_V+\varepsilon_C)},\quad \mu=\frac{\varepsilon_C+\varepsilon_V}{2}+\frac34k_BT\ln\left(\frac{m_p^*}{m_n^*}\right)$$
$$\mu=\frac{e\tau}{m^*},\quad \sigma=e(n\mu_n+p\mu_p),\quad E_g=\varepsilon_C-\varepsilon_V$$
$$n=p=\sqrt{N_CN_V}e^{-\frac{\beta E_g}{2}}\quad \text{si intrínseco}$$

Semiconductores dopados ($n=1$ ionización) $\varepsilon=\varepsilon_0\varepsilon_r$

$$E_n=\frac{m^*e^4}{2(4\pi\varepsilon\hbar)^2}\frac{1}{n^2},\quad r_n=\varepsilon\frac{4\pi\hbar^2}{m^*e^2}n^2$$
$$n_n\approx\frac{2N_D}{1+\sqrt{1+4\frac{N_D}{N_C}e^{\beta E_d}}}$$

Unión p-n

$$n_n=N_Ce^{\beta(\mu-\varepsilon_C^n)};\quad p_p=N_Ve^{\beta(\varepsilon_V^p-\mu)}$$
$$d_n^0=\sqrt{\frac{2\varepsilon V_D}{e}\frac{N_A/N_D}{N_A+N_D}};\quad d_p^0=\sqrt{\frac{2\varepsilon V_D}{e}\frac{N_D/N_A}{N_A+N_D}}$$
$$d_n(V)=d_n^0\sqrt{\frac{V_D-V}{V_D}};\quad d_p(V)=d_p^0\sqrt{\frac{V_D-V}{V_D}}$$

ancho de zona de carga espacial $=d_n(V)+d_p(V)$

$$eV_D=k_BT\ln\left(\frac{n_np_p}{n_i^2}\right);\quad I(V)=(I_n^{gen}+I_p^{gen})(e^{\beta eV}-1)$$

p-Dopado ($N_A\gg N_D$):

- T bajas $\Rightarrow p\approx N_Ve^{-\beta E_A}$
- T intermedias $\Rightarrow p\approx N_A-N_D$
- T alta $\Rightarrow p=n=\sqrt{N_CN_V}e^{-\beta\frac{E_g}{2}}$

5 Mates

$$\sin^2\left(\frac x2\right)=\frac{1-\cos a}{2}$$
$$\int_0^\infty\frac{1}{e^x-1}dx=+\infty,\quad\int_0^\infty\frac{1}{e^x+1}dx=\ln(2)$$
$$\int_0^\infty\frac{x}{e^x-1}dx=\frac{\pi^2}{6},\quad\int_0^\infty\frac{x}{e^x+1}dx=\frac{\pi^2}{12}$$
$$\int_0^\infty\frac{x^2}{e^x-1}dx=2\zeta(3),\quad\int_0^\infty\frac{x^2}{e^x+1}dx=\frac32\zeta(3)$$
$$\int_0^\infty\frac{x^3}{e^x-1}dx=\frac{\pi^4}{15},\quad\int_0^\infty\frac{x^3}{e^x+1}dx=\frac{7\pi^4}{120}$$